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APPLICATION NO. FILING DATE		ILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/670,194		09/26/2003	Toshio Kimura	1035-471	4479	
23117	7590	10/06/2004		EXAMINER		
		RHYE, PC	VU, QUANG D			
1100 N GLI 8TH FLOO		D	ART UNIT	PAPER NUMBER		
ARLINGTO	ON, VA	22201-4714	2811			

DATE MAILED: 10/06/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

		Applicati	Application No. Applicant(s) 10/670,194 KIMURA ET AL.						
		10/670,19							
	Office Action Summary	Examine	•	Art Unit					
		Quang D		2811	pv				
Period fo	The MAILING DATE of this communic or Reply	cation appears on the	e cover sheet with the c	orrespondence add	iress				
THE I - Exter after - If the - If NO - Failu Any r	ORTENED STATUTORY PERIOD FOMAILING DATE OF THIS COMMUNIC sions of time may be available under the provisions of SIX (6) MONTHS from the mailing date of this commuperiod for reply specified above is less than thirty (30 period for reply is specified above, the maximum state to reply within the set or extended period for reply veply received by the Office later than three months afted patent term adjustment. See 37 CFR 1.704(b).	CATION. of 37 CFR 1.136(a). In no evunication. of days, a reply within the state tutory period will apply and will, by statute, cause the app	ent, however, may a reply be tin utory minimum of thirty (30) day ill expire SIX (6) MONTHS from lication to become ABANDONE	nely filed s will be considered timely. the mailing date of this cor D (35 U.S.C. § 133).					
Status									
1)🖂	Responsive to communication(s) filed	d on <u>14 July 2004</u> .							
2a) <u></u> □	This action is FINAL . 2	b)⊠ This action is n	on-final.						
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.								
Dispositi	on of Claims								
5)□ 6)⊠ 7)□	•								
Applicati	on Papers								
• —	The specification is objected to by the								
10)	The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.								
•	Applicant may not request that any object	•	•	, ,					
11)	Replacement drawing sheet(s) including The oath or declaration is objected to	•	• , ,		• •				
Priority u	ınder 35 U.S.C. § 119								
12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.									
Attachment	t(s) e of References Cited (PTO-892)		4) Interview Summer	(PTO-413)					
2) Notice 3) Notice	e of References Cited (P10-892) e of Draftsperson's Patent Drawing Review (P1 nation Disclosure Statement(s) (PTO-1449 or F r No(s)/Mail Date 02/04/04.		4) Interview Summary Paper No(s)/Mail Da 5) Notice of Informal P 6) Other:	ate	.152)				

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DETAILED ACTION

Election/Restrictions

Applicant's election without traverse of group I (claims 1-10) in the reply filed on 07/14/04 is acknowledged.

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1-10 are rejected under 35 U.S.C. 102(b) as being anticipated by US Patent No. 6,236,115 to Gaynes et al.

Regarding claim 1, Gaynes et al. (figures 1-9B, 13A-B) teach a chip-stack semiconductor device, comprising multiple semiconductor chips (30a, 30b, 30c) vertically stacked on top of each other, wherein:

each of the semiconductor chips (30a, 30b, 30c) includes multiple through electrodes (via electrodes are formed on both side of the chips) (column 10, lines 40-56) connected to each other in regions inside of electrode pads (33) derived from a device region, each of the through electrodes (via electrodes) linking a front surface (top surface of chip) to a back (bottom surface of chip) surface of the semiconductor chip.

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Regarding claim 2, Gaynes et al. teach the electrode pads (33) are provided along a periphery of the semiconductor chip (30a, 30b, 30c) so as to surround the device region.

Regarding claim 3, Gaynes et al. teach at least one type of the through electrodes (via electrodes) is contact through electrodes electrically connected to the electrode pad (33).

Regarding claim 4, Gaynes et al. teach at least one type of the through electrodes (via electrodes) is contact through electrodes electrically connected to the electrode pad (33).

Regarding claim 5, Gaynes et al. teach at least one type of the through electrodes (middle layer [33] located on the chip [30b] or chip [30c]) is non-contact through electrodes not electrically connected to the electrode pad (right [33]).

Regarding claim 6, Gaynes et al. teach at least one type of the through electrodes (middle layer [33] is located on the chip [30b] or chip [30c]) is non-contact through electrodes not electrically connected to the electrode pad (right [33]).

Regarding claim 7, Gaynes et al. teach a through electrode (via electrode) is further provided in regions outside (via electrode is located in a distance from the middle layer [33]) of the electrode pad (middle layer [33]).

Regarding claim 8, Gaynes et al. teach a through electrode (via electrode) is further provided in regions outside (via electrode is located in a distance from the middle layer [33]) of the electrode pad (middle layer [33]).

Regarding claim 9, Gaynes et al. teach the solder (Pb, Sn), which is formed between the via electrodes of the chips. Gaynes et al. teach the pads, connections and solders, which are formed on both side of the chips (column 10, lines 40-56). Therefore, Gaynes et al. teach the through electrodes (via electrodes) in the semiconductor chips (30a, 30b, 30c) are connected to

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each other via bumps (solder Pb, Sn) so that the semiconductor chips are vertically stacked on top of each other.

Regarding claim 10, Gaynes et al. teach the solder (Pb, Sn), which is formed between the via electrodes of the chips. Gaynes et al. teach the pads, connections and solders, which are formed on both side of the chips (column 10, lines 40-56). Therefore, Gaynes et al. teach the through electrodes (via electrodes) in the semiconductor chips (30a, 30b, 30c) are connected to each other via bumps (solder Pn, Sn) so that the semiconductor chips are vertically stacked on top of each other.

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Quang D Vu whose telephone number is 571-272-1667. The examiner can normally be reached on Monday-Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

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